



A Product Line of Diodes Incorporated



ZX5T3Z

40V PNP HIGH GAIN LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

Features

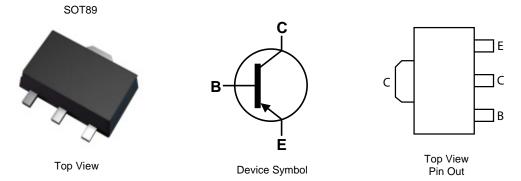
- BV_{CEO} > -40V
- I_C = -5.5A High Continuous Current
- I_{CM} = -15A Peak Pulse Current
- R_{CE(SAT)} = 29mΩ for a low equivalent On-Resistance
- Low Saturation Voltage V_{CE(SAT)} < -60mV @ -1A
- hFE Specified Up to -10A for High Current Gain Hold Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ⁽²⁾
- Weight: 0.05 grams (Approximate)

Applications

- Charging Circuits
- DC-DC Converters
- MOSFET and IGBT Gate Driving
- Power Switches
- Motor Control



Ordering Information (Note 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZX5T3ZTA	AEC-Q101	53Z	7	12	1,000
ZX5T3ZQTA	Automotive	53Z	7	12	1,000
ZX5T3ZTC	AEC-Q101	53Z	13	12	4,000
ZX5T3ZQTC	Automotive	53Z	13	12	4,000

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

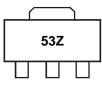
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.

5. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



53Z = Product Type Marking Code





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	Vсво	-50	V
Collector-Base Voltage	V _{CBS}	-50	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-7.5	V
Continuous Collector Current	lc	-5.5	A
Peak Pulse Current	I _{CM}	-15	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		0.9		
Dever Dissignation	(Note 7)		1.5	w	
Power Dissipation	(Note 8)	P _D	2.1	vv	
	(Note 9)		3.0		
	(Note 6)		139	0000	
Thermal Resistance, Junction to Ambient Air	(Note 7)		83	°C/W	
	(Note 8)	R _{θJA}	60		
	(Note 9)		42		
Thermal Resistance, Junction to Lead (Note 10)		R _{θJL}	2.81	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state. Notes:

7. Same as note (6), except the device is mounted on 25mm x 25mm 1oz copper.

8. Same as note (6), except the device is mounted on 50mm x 50mm 1oz copper.

9. Same as note (6), except the device is mounted on 25mm x 25mm 1oz copper and measured at t<5secs.

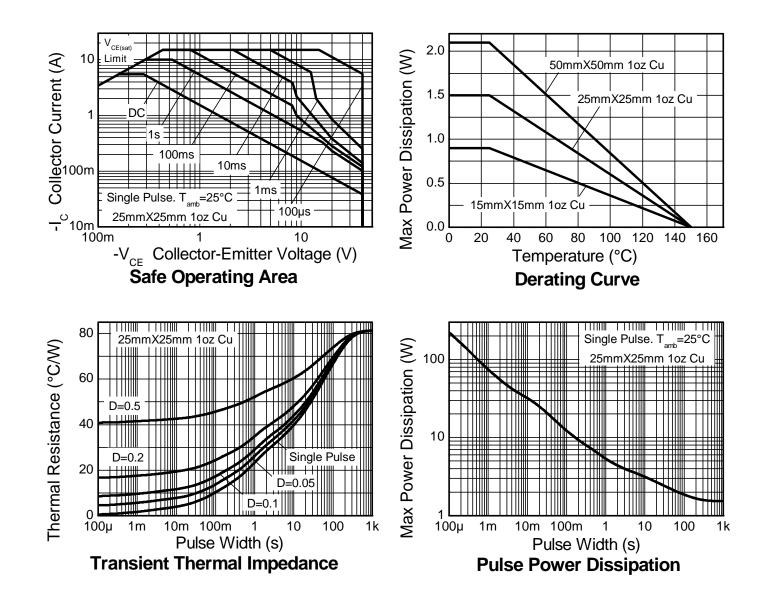
10. Thermal resistance from junction to solder-point (on the exposed collector pad).

11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating Information







Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

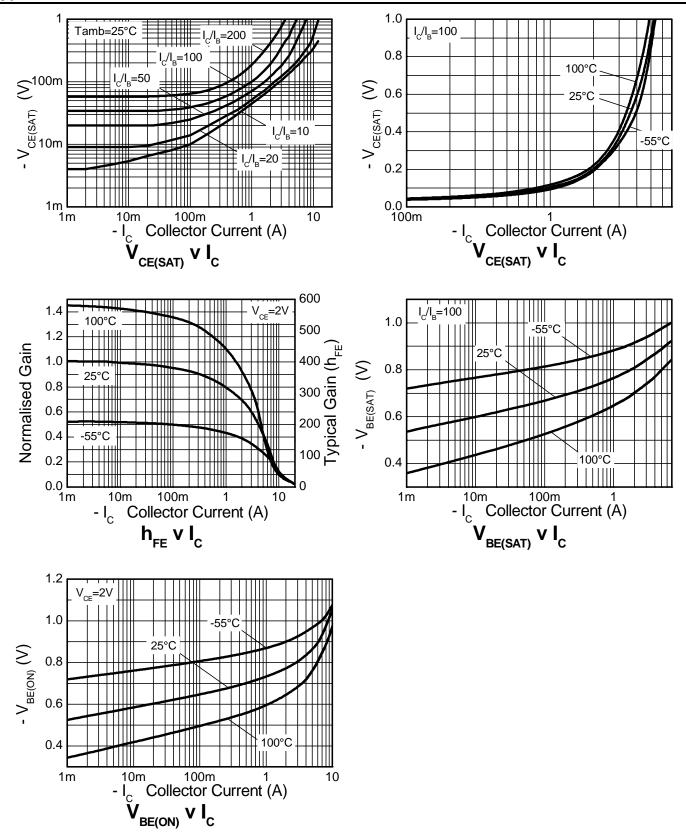
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50	-90	—	V	I _C = -100μΑ
Collector-Emitter Breakdown Voltage	BV _{CES}	-50	-90	—	V	I _C = -100μΑ
Collector-Emitter Breakdown Voltage (Note 12)	BV _{CEO}	-40	-58	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7.5	-8.3	—	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	_	<1	-20	nA	V _{CB} = -40V
Collector Cutoff Current	I _{CES}	_	<1	-20	nA	V _{CE} = -32V
Emitter Cutoff Current	I _{EBO}	_	<1	-20	nA	V _{EB} = -6V
DC Current Transfer Static Ratio (Note 12)	h _{FE}	200 200 170 110	390 350 290 175	 550 	_	$\label{eq:linear} \begin{array}{l} I_{C} = -10 \text{mA}, \ V_{CE} = -2 \text{V} \\ I_{C} = -0.5 \text{A}, \ V_{CE} = -2 \text{V} \\ I_{C} = -2 \text{A}, \ V_{CE} = -2 \text{V} \\ I_{C} = -5.5 \text{A}, \ V_{CE} = -2 \text{V} \end{array}$
Collector-Emitter Saturation Voltage (Note 12)	V _{CE} (sat)		-15 -44 -50 -120 -70 -125 -130 -162	-30 -60 -70 -165 -80 -175 -175 -185	mV	$ \begin{array}{l} I_{C} = -0.1A, \ I_{B} = -10mA \\ I_{C} = -1A, \ I_{B} = -100mA \\ I_{C} = -1A, \ I_{B} = -50mA \\ I_{C} = -1A, \ I_{B} = -10mA \\ I_{C} = -2A, \ I_{B} = -200mA \\ I_{C} = -2A, \ I_{B} = -200mA \\ I_{C} = -2A, \ I_{B} = -40mA \\ I_{C} = -3.5A, \ I_{B} = -175mA \\ I_{C} = -5.5A, \ I_{B} = -550mA \end{array} $
Base-Emitter Saturation Voltage (Note 12)	V _{BE(SAT)}	_	-820 -1000	-900 -1075	V	I _C = -2A, I _B = -40mA I _C = -5.5A, I _B = -550mA
Base-Emitter Turn-On Voltage (Note 12)	V _{BE(ON)}	_	-778 -869	-850 -950	V	I _C = -2A, V _{CE} = -2V I _C = -5.5A, V _{CE} = -2V
Transitional Frequency	f _T	_	152	_	MHz	Ic = -50mA, V _{CE} = -10V f = 100MHz
Output Capacitance	Cobo	—	53	—	pF	V_{CB} = -10V, f = 1MHz,
Switching Times	t _d t _r t _s t _f		18 17 325 60		nS	$I_{C} = -1A, V_{CC} = -10V$ $I_{B1} = -I_{B2} = -100mA$
Switching Times	t _d t _r t _s t _f		55 107 264 103	- -	nS	$I_{C} = -2A, V_{CC} = -30V$ $I_{B1} = -I_{B2} = -20mA$

Note: 12. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.





Typical Electrical Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

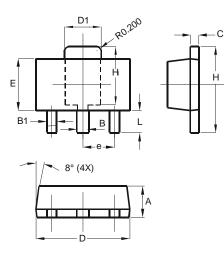






Package Outline Dimensions

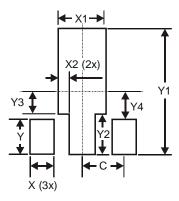
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT89					
Dim	Min	Max				
Α	1.40	1.60				
В	0.44	0.62				
B1	0.35	0.54				
С	0.35 0.44					
D	4.40	4.60				
D1	1.62	1.83				
Е	2.29	2.60				
е	1.50 Typ					
Н	3.94 4.25					
H1	2.63 2.93					
L	0.89	1.20				
All C	All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimension	Malas (la asso)
Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500





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